

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Plastic Medium Power Silicon PNP Transistor

This series of plastic, medium-power silicon PNP transistors can be used for for amplifier and switching applications. Complementary types are BD437 and BD441.

Features

• These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|-----------------------------------|----------------------|-----------|
| Collector-Emitter Voltage BD436G BD438G BD440G BD442G | V _{CEO} | 32 45 60 80 | Vdc |
| Collector-Base Voltage BD436G BD438G BD440G BD442G | V _{CBO} | 32 45 60 80 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 5.0 | Vdc |
| Collector Current | I _C | 4.0 | Adc |
| Base Current | I _B | 1.0 | Adc |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 36 288 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

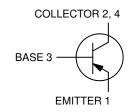
| Characteristic | Symbol | Max | Unit |
|--------------------------------------|-----------------|-----|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 3.5 | °C/W |



ON Semiconductor®

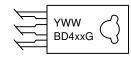
http://onsemi.com

4.0 AMP POWER TRANSISTORS PNP SILICON





MARKING DIAGRAM



Y = Year WW = Work Week BD4xx = Device Code

xx = 36, 36T, 38, 38T, 40, 42

G = Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping |
|---------|---------------------|---------------|
| BD436G | TO-225 (Pb-Free) | 500 Units/Box |
| BD436TG | TO-225 (Pb-Free) | 50 Units/Rail |
| BD438G | TO-225 (Pb-Free) | 500 Units/Box |
| BD438TG | TO-225 (Pb-Free) | 50 Units/Rail |
| BD440G | TO-225 (Pb-Free) | 500 Units/Box |
| BD442G | TO-225 (Pb-Free) | 500 Units/Box |

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|-----------------------|----------------------|------------------|--------------------------|------|
| Collector–Emitter Breakdown Voltage (I _C = 100 mA, I _B = 0) BD436G BD438G BD440G BD442G | V _(BR) CEO | 32 45 60 80 | - - - | - - - | Vdc |
| Collector-Base Breakdown Voltage (I _C = 100 μA, I _B = 0) BD436G BD438G BD440G BD442G | V _(BR) CBO | 32 45 60 80 | - - - - | - - - - | Vdc |
| Emitter–Base Breakdown Voltage $(I_E = 100 \mu A, I_C = 0)$ | V _{(BR)EBO} | 5.0 | - | - | Vdc |
| Collector Cutoff Current $(V_{CB} = 32 \text{ V}, I_E = 0)$ BD436G $(V_{CB} = 45 \text{ V}, I_E = 0)$ BD438G $(V_{CB} = 60 \text{ V}, I_E = 0)$ BD440G $(V_{CB} = 80 \text{ V}, I_E = 0)$ BD442G | Ісво | - - - | - - - | 0.1 0.1 0.1 0.1 | mAdc |
| Emitter Cutoff Current (V _{EB} = 5.0 V) | I _{EBO} | _ | - | 1.0 | mAdc |
| DC Current Gain (I _C = 10 mA, V _{CE} = 5.0 V) BD436G BD438G BD440G BD442G | h _{FE} | 40 30 20 15 | - - - - | - - - - | - |
| DC Current Gain (I _C = 500 mA, V _{CE} = 1.0 V) BD436G BD438G BD440G BD442G | h _{FE} | 85 85 40 40 | - - - - | 475 475 475 475 | - |
| DC Current Gain (I _C = 2.0 A, V _{CE} = 1.0 V) BD436G BD438G BD440G BD442G | h _{FE} | 50 40 25 15 | - - - - | - - - - | - |
| Collector Saturation Voltage $ \begin{array}{l} \text{(I}_C=2.0 \text{ A, I}_B=0.2 \text{ A)} \\ \text{BD436G} \\ \text{(I}_C=3.0 \text{ A, I}_B=0.3 \text{ A)} \\ \text{BD438G} \\ \text{BD440G} \\ \text{BD442G} \end{array} $ | V _{CE} (sat) | - - - | - - - | 0.5 0.7 0.8 0.8 | Vdc |
| BD442G Base-Emitter On Voltage (I _C = 2.0 A, V _{CE} = 1.0 V) BD436G/BD438G BD440G/BD442G | V _{BE(ON)} | <u> </u> | - - - | 1.1 1.5 | Vdc |
| Current–Gain – Bandwidth Product (V _{CE} = 1.0 V, I _C = 250 mA, f = 1.0 MHz) | f _T | 3.0 | - | - | MHz |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

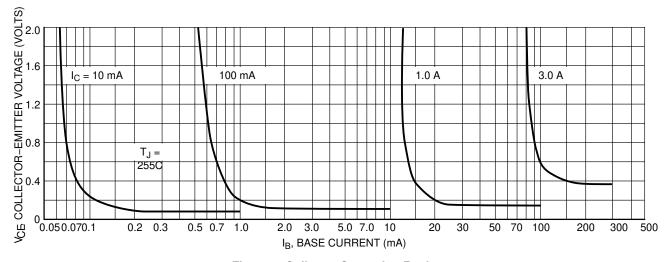


Figure 1. Collector Saturation Region

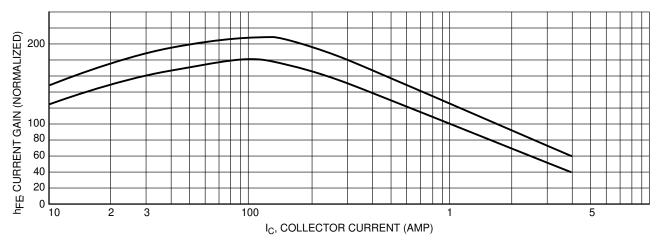


Figure 2. Current Gain

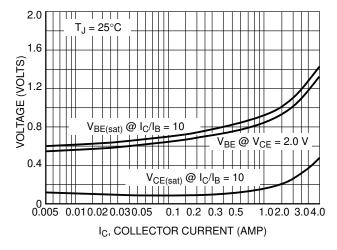


Figure 3. "On" Voltage

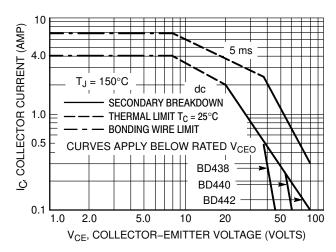
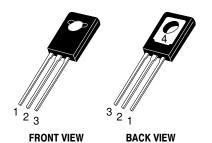
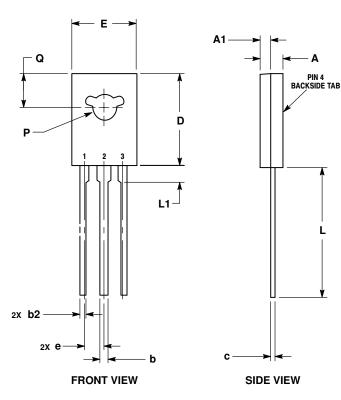


Figure 4. Active Region Safe Operating Area

PACKAGE DIMENSIONS



TO-225 CASE 77-09 ISSUE AC



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

| | MILLIMETERS | | |
|-----|-------------|-------|--|
| DIM | MIN | MAX | |
| Α | 2.40 | 3.00 | |
| A1 | 1.00 | 1.50 | |
| b | 0.60 | 0.90 | |
| b2 | 0.51 | 0.88 | |
| С | 0.39 | 0.63 | |
| D | 10.60 | 11.10 | |
| Е | 7.40 | 7.80 | |
| е | 2.04 | 2.54 | |
| L | 14.50 | 16.63 | |
| L1 | 1.27 | 2.54 | |
| Р | 2.90 | 3.30 | |
| Q | 3.80 | 4.20 | |

PIN 1 FMITTER COLLECTOR 2., 4.

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